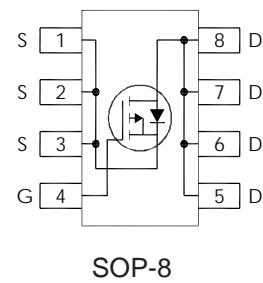


## Applications

- Charge and Discharge Switch for Notebook PC  
Battery Application



## Features

- $V_{DS} (V) = -30V$
- $I_D = -16A$  ( $V_{GS} = -10V$ )
- $R_{DS(ON)} < 6.6m\Omega$  ( $V_{GS}=-10V$ )
- $R_{DS(ON)} < 10.2 m\Omega$  ( $V_{GS}=-4.5V$ )

## Features

Industry-Standard SO8 Package

RoHS Compliant Containing no Lead, no Bromide and no Halogen

## Resulting Benefits

Multi-Vendor Compatibility

Environmentally Friendlier

## Absolute Maximum Ratings

	Parameter	Max.	Units
$V_{DS}$	Drain-to-Source Voltage	-30	V
$V$	Gate-to-Source Voltage	$\pm 20$	
$I$ @ $T_A = 25^\circ C$	Continuous Drain Current, $V_{GS} @ 10V$	-16	A
$I$ @ $T_A = 70^\circ C$	Continuous Drain Current, $V_{GS} @ 10V$	-13	
$I$	Pulsed Drain Current ①	-130	
$P$ @ $T_A = 25^\circ C$	Power Dissipation ④	2.5	W
$P$ @ $T_A = 70^\circ C$	Power Dissipation ④	1.6	
	Linear Derating Factor	0.02	W/ $^\circ C$
$T$	Operating Junction and Storage Temperature Range	-55 to + 150	$^\circ C$

**Static @  $T_J = 25^\circ\text{C}$  (unless otherwise specified)**

	Parameter	Min.	Typ.	Max.	Units	Conditions
$\text{BV}_{\text{DSS}}$	Drain-to-Source Breakdown Voltage	-30			V	$V_{\text{GS}} = 0\text{V}, I_D = -250\mu\text{A}$
$\Delta \text{BV}_{\text{DSS}/\Delta T_J}$	Breakdown Voltage Temp. Coefficient		0.022		$\text{V}/^\circ\text{C}$	Reference to $25^\circ\text{C}$ , $I_D = -1\text{mA}$
$R_{\text{DS(on)}}$	Static Drain-to-Source On-Resistance		5.4	6.6	$\text{m}\Omega$	$V_{\text{GS}} = -10\text{V}, I_D = -16\text{A}$ ③
			8.3	10.2		$V_{\text{GS}} = -4.5\text{V}, I_D = -13\text{A}$ ③
$V_{\text{GS(th)}}$	Gate Threshold Voltage	-1.3	-1.8	-2.4	V	
$\Delta V_{\text{GS(th)}}$	Gate Threshold Voltage Coefficient		-5.7		$\text{mV}/^\circ\text{C}$	
$I_{\text{DSS}}$	Drain-to-Source Leakage Current			-1.0	$\mu\text{A}$	$V_{\text{DS}} = -24\text{V}, V_{\text{GS}} = 0\text{V}$
				-150		$V_{\text{DS}} = -24\text{V}, V_{\text{GS}} = 0\text{V}, T_J = 125^\circ\text{C}$
$I_{\text{GSS}}$	Gate-to-Source Forward Leakage			-100	nA	$V_{\text{GS}} = -20\text{V}$
	Gate-to-Source Reverse Leakage			100		$V_{\text{GS}} = 20\text{V}$
$g_{\text{fs}}$	Forward Transconductance	36			S	$V_{\text{DS}} = -10\text{V}, I_D = -13\text{A}$
$Q_g$	Total Gate Charge ⑥		31		nC	$V_{\text{DS}} = -15\text{V}, V_{\text{GS}} = -4.5\text{V}, I_D = -13\text{A}$
$Q_g$	Total Gate Charge ⑥		61	92		$V_{\text{GS}} = -10\text{V}$
$Q_{\text{qs}}$	Gate-to-Source Charge ⑥		9		nC	$V_{\text{DS}} = -15\text{V}$
$Q_{\text{qd}}$	Gate-to-Drain Charge ⑥		14			$I_D = -13\text{A}$
$R_G$	Gate Resistance ⑥		14		$\Omega$	
$t_{\text{d(on)}}$	Turn-On Delay Time		19		ns	$V_{\text{DD}} = -15\text{V}, V_{\text{GS}} = -4.5\text{V}$ ③
$t_r$	Rise Time		64			$I_D = -1.0\text{A}$
$t_{\text{d(off)}}$	Turn-Off Delay Time		160			$R_G = 6.8\Omega$
$t_f$	Fall Time		120			See Figs. 20a & 20b
$C_{\text{iss}}$	Input Capacitance		2820		pF	$V_{\text{GS}} = 0\text{V}$
$C_{\text{oss}}$	Output Capacitance		640			$V_{\text{DS}} = -15\text{V}$
$C_{\text{rss}}$	Reverse Transfer Capacitance		370			$f = 1.0\text{MHz}$

**Avalanche Characteristics**

	Parameter	Typ.	Max.	Units
$E_{\text{AS}}$	Single Pulse Avalanche Energy ②		330	mJ
$I_{\text{AR}}$	Avalanche Current ①		-13	A

**Diode Characteristics**

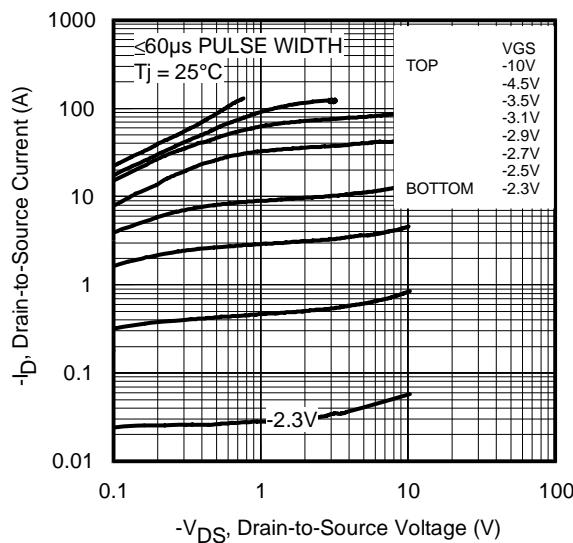
	Parameter	Min.	Typ.	Max.	Units	Conditions
$I_S$	Continuous Source Current (Body Diode)			-2.5	A	MOSFET symbol showing the integral reverse p-n junction diode.
$I_{\text{SM}}$	Pulsed Source Current (Body Diode) ①			-130		
$V_{\text{SD}}$	Diode Forward Voltage			-1.2	V	$T_J = 25^\circ\text{C}, I_S = -2.5\text{A}, V_{\text{GS}} = 0\text{V}$ ③
$t_{\text{rr}}$	Reverse Recovery Time		33	50	ns	$T_J = 25^\circ\text{C}, I_F = -2.5\text{A}, V_{\text{DD}} = -24\text{V}$
$Q_{\text{rr}}$	Reverse Recovery Charge		30	45	nC	$dI/dt = 100\text{A}/\mu\text{s}$ ③

**Thermal Resistance**

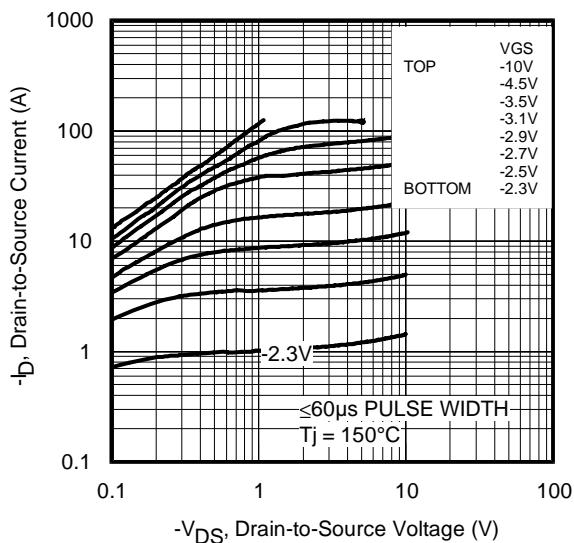
	Parameter	Typ.	Max.	Units
$R_{\text{DjL}}$	Junction-to-Drain Lead ⑤		20	$^\circ\text{C}/\text{W}$
$R_{\text{DjA}}$	Junction-to-Ambient ④		50	

**Notes:**

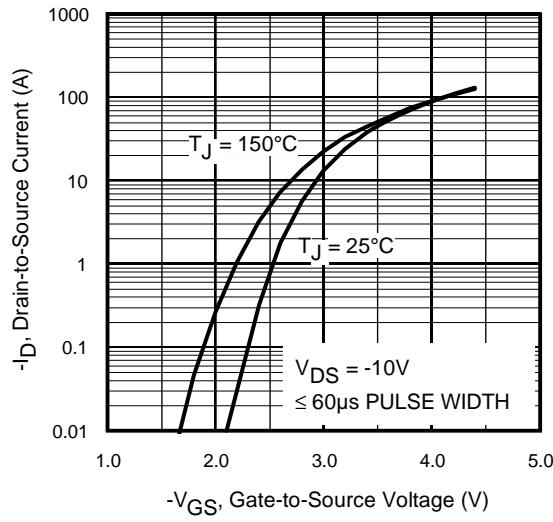
- ① Repetitive rating; pulse width limited by max. junction temperature.
- ② Starting  $T_J = 25^\circ\text{C}$ ,  $L = 4.3\text{mH}$ ,  $R_G = 25\Omega$ ,  $I_{\text{AS}} = -13\text{A}$ .
- ③ Pulse width  $\leq 400\mu\text{s}$ ; duty cycle  $\leq 2\%$ .
- ④ When mounted on 1 inch square copper board.
- ⑤  $R_\theta$  is measured at  $T_J$  of approximately  $90^\circ\text{C}$ .



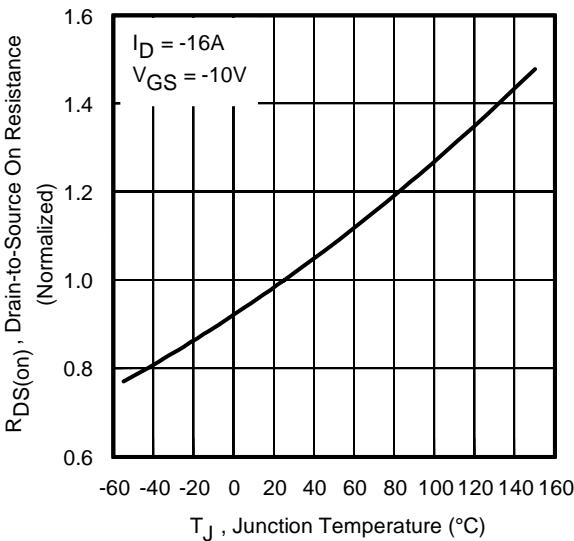
**Fig 1.** Typical Output Characteristics



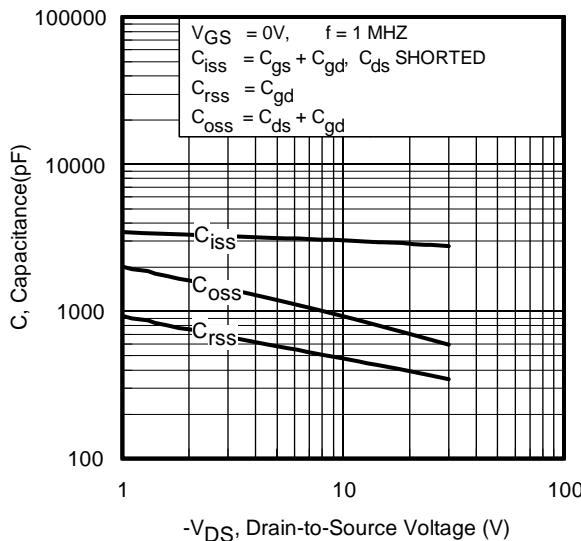
**Fig 2.** Typical Output Characteristics



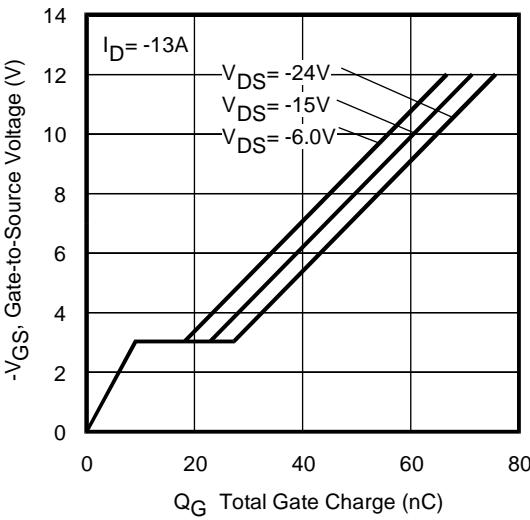
**Fig 3.** Typical Transfer Characteristics



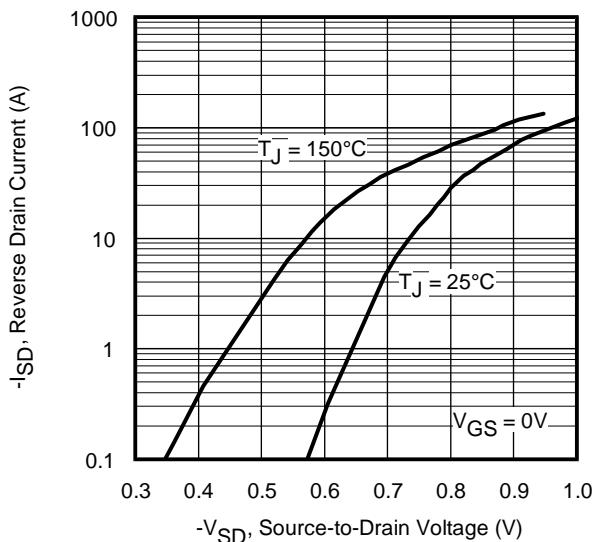
**Fig 4.** Normalized On-Resistance vs. Temperature



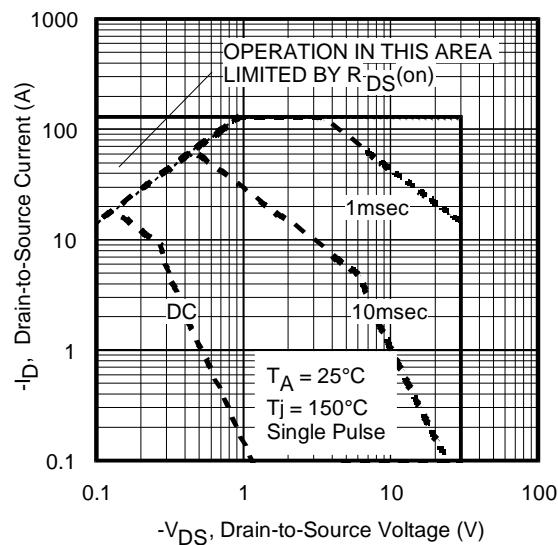
**Fig 5.** Typical Capacitance vs.Drain-to-Source Voltage



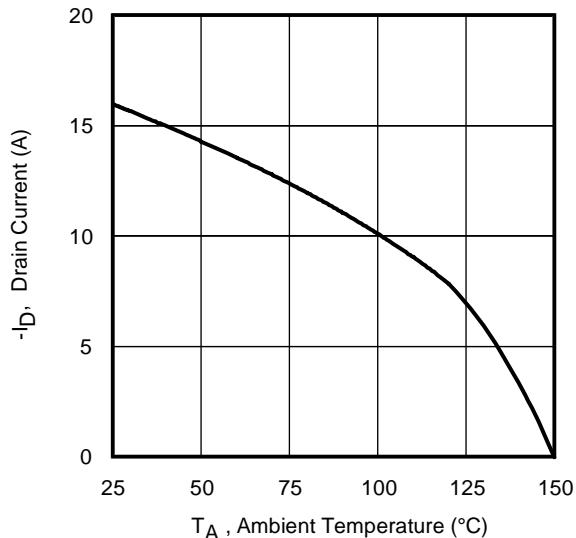
**Fig 6.** Typical Gate Charge vs.Gate-to-Source Voltage



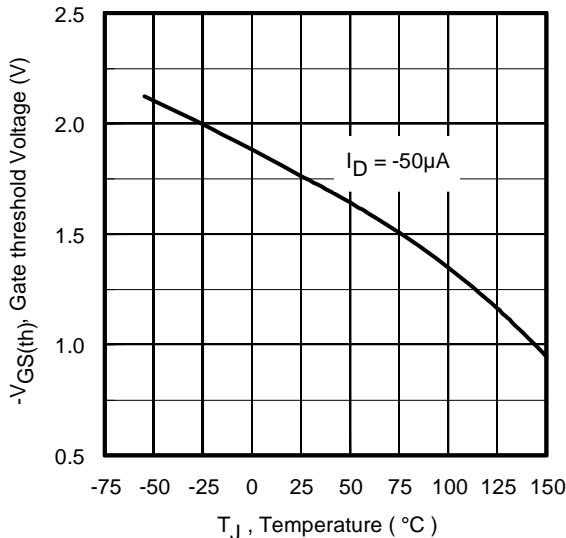
**Fig 7.** Typical Source-Drain Diode Forward Voltage



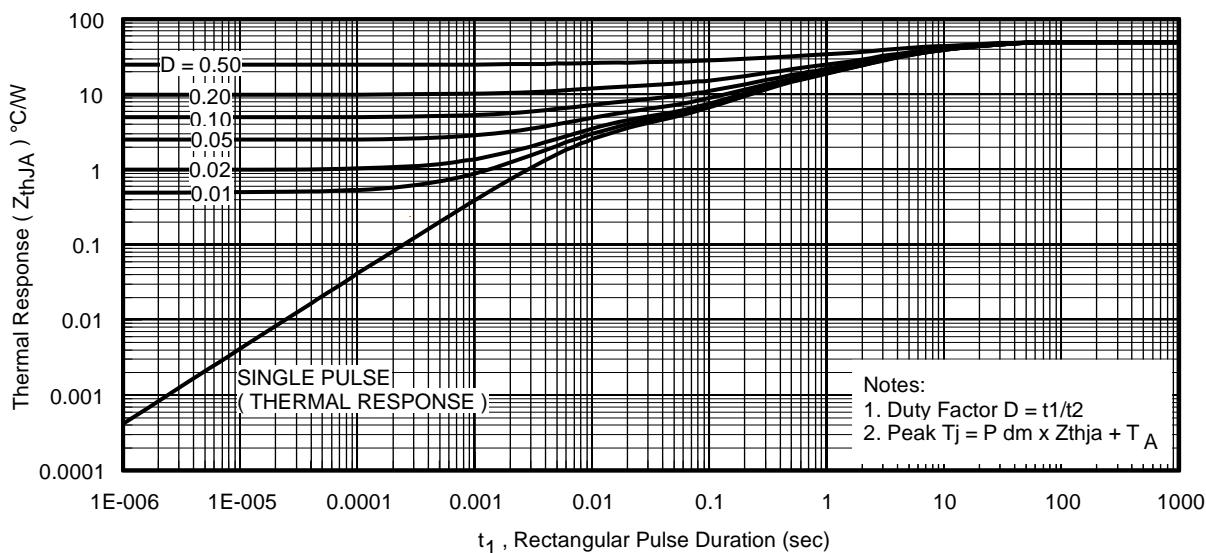
**Fig 8.** Maximum Safe Operating Area



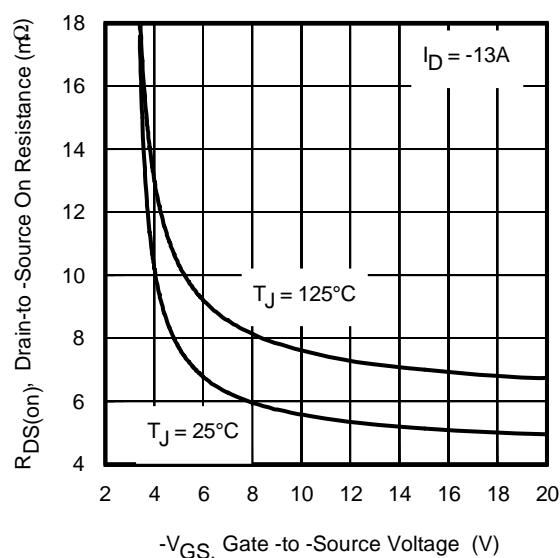
**Fig 9.** Maximum Drain Current vs. Ambient Temperature



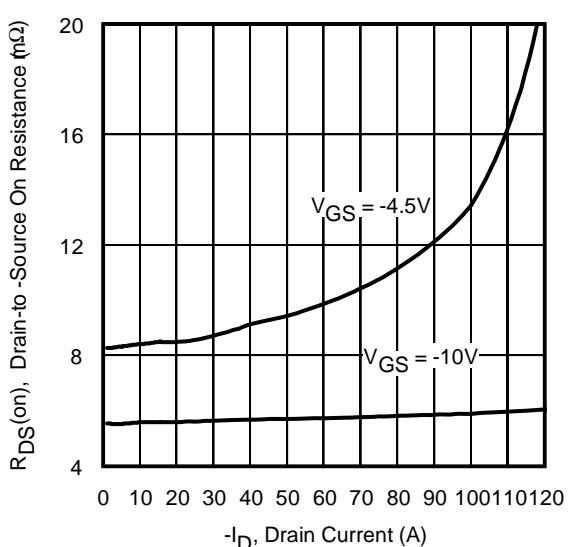
**Fig 10.** Threshold Voltage vs. Temperature



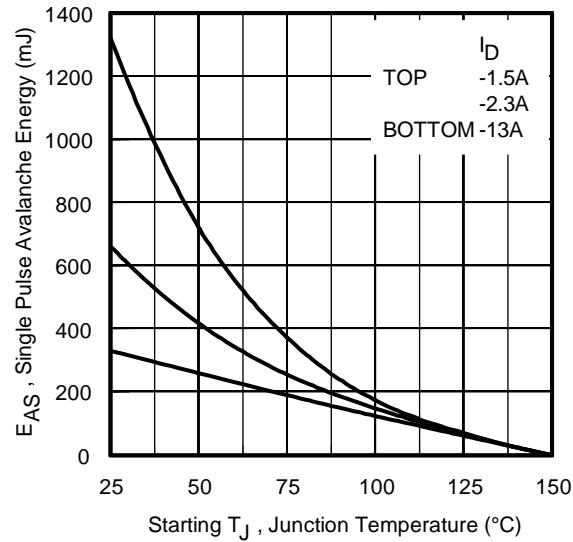
**Fig 11.** Maximum Effective Transient Thermal Impedance, Junction-to-Ambient



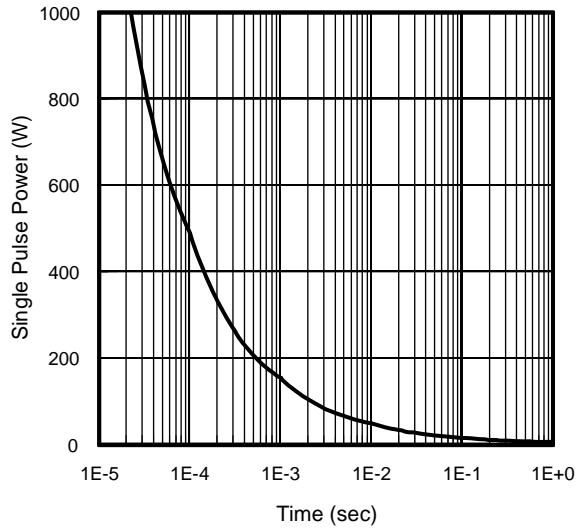
**Fig 12.** On-Resistance vs. Gate Voltage



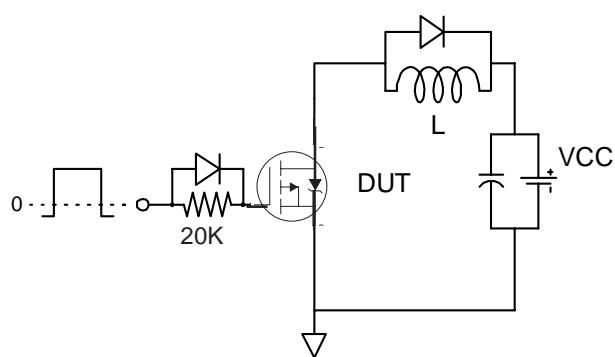
**Fig 13.** Typical On-Resistance vs. Drain Current



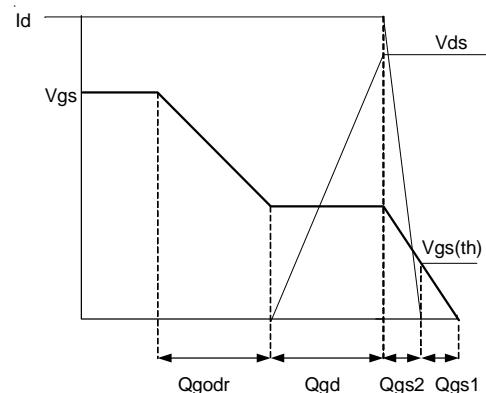
**Fig 14.** Maximum Avalanche Energy vs. Drain Current



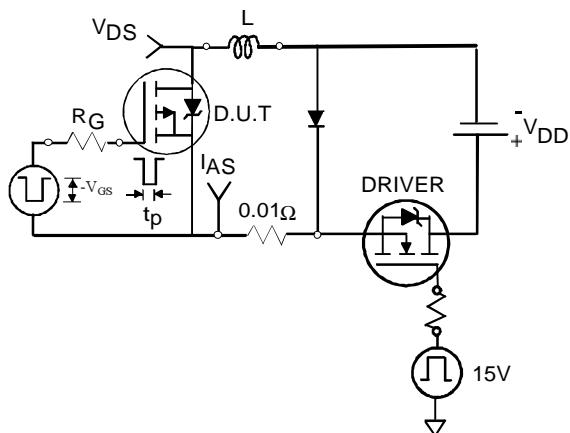
**Fig 16.** Typical Power vs. Time



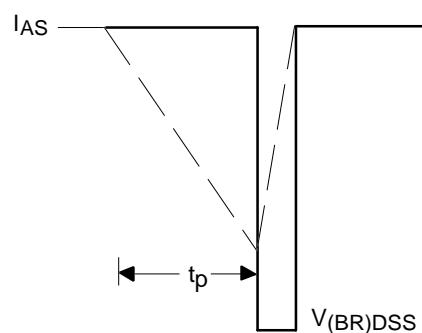
**Fig 17a.** Gate Charge Test Circuit



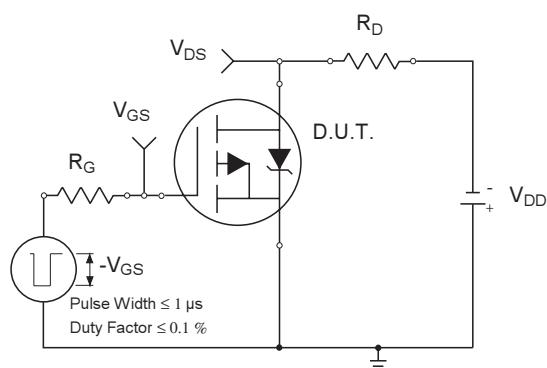
**Fig 17b.** Gate Charge Waveform



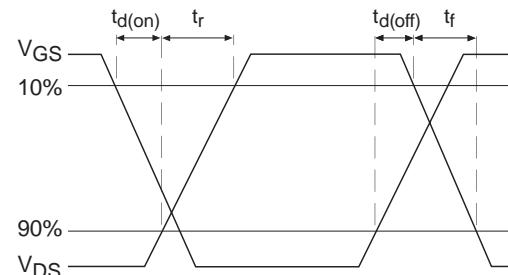
**Fig 18a.** Unclamped Inductive Test Circuit



**Fig 18b.** Unclamped Inductive Waveforms

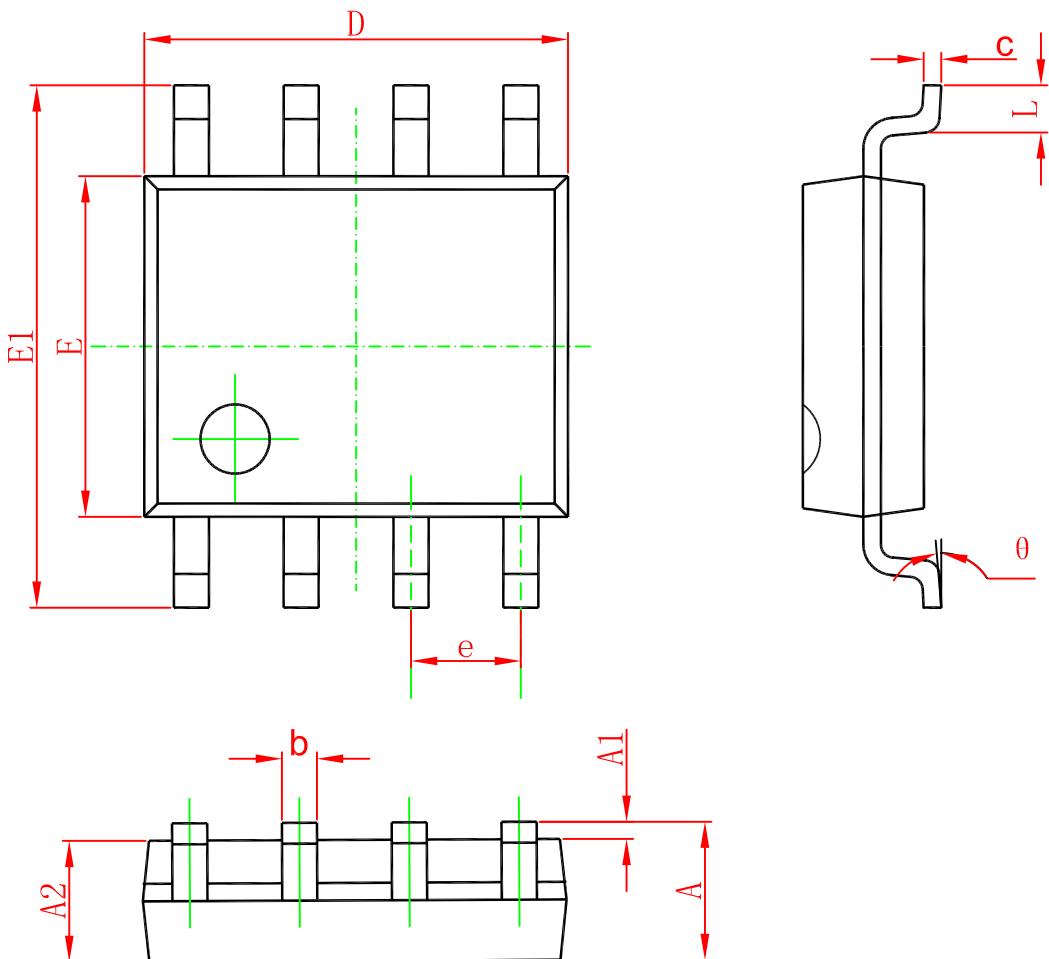


**Fig 19a.** Switching Time Test Circuit



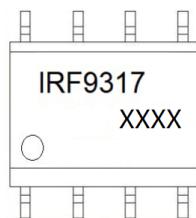
**Fig 19b.** Switching Time Waveforms

**Package Mechanical Data SOP-8**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

## Marking



## Ordering information

Order code	Package	Baseqty	Deliverymode
IRF9317	SOP-8	3000	Tape and reel